### Description

The FPF1504/FPF1504L are low- $R_{DS}$  P-channel MOSFET load switches of the IntelliMAX<sup>TM</sup> family. Integrated slew-rate control prevents excessive inrush current from the supply rails with capacitive loads common in power applications. In addition, the FPF1504/FPF1504L feature output discharge capability.

The input voltage range operates from 1.0 V to 3.6 V to fulfill today's mobile device supply requirements. Switch control is by a logic input (ON pin) capable of interfacing directly with low-voltage CMOS control signals and GPIOs in embedded processors.

### Features

- 1.0 V to 3.6 V Input Voltage Operating Range
- Typical R<sub>DS(ON)</sub>:
  - 15 m $\Omega$  at V<sub>IN</sub> = 3.3 V
  - + 20 m $\Omega$  at V<sub>IN</sub> = 1.8 V
  - 40 m $\Omega$  at V<sub>IN</sub> = 1.0 V
- Slew Rate Control
- Output Discharge Function
- Low <1  $\mu$ A Quiescent Current at V<sub>ON</sub> = V<sub>IN</sub>
- ESD Protected: 4000 V HBM, 2000 V CDM
- GPIO/CMOS-Compatible Enable Circuitry
- Active HIGH and active LOW versions

### Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Digital Cameras
- Advanced Notebook, UMPC, and MID
- Portable Medical Devices
- GPS and Navigation Equipment

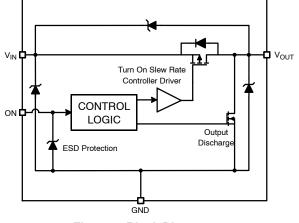


Figure 1. Block Diagram



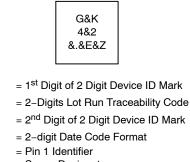
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WLCSP4 CASE 567RH

### MARKING DIAGRAM



= Space Designator

G

&K

4

&2 &.

&Ε

&Z = Assembly Plant Code

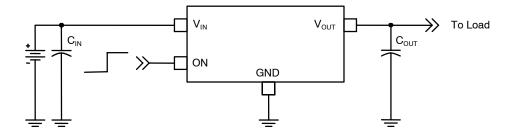
### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

### **ORDERING INFORMATION**

Part Number	Top Mark	Switch (Typical) At 1.8 V <sub>IN</sub>	Input Buffer	Output Discharge	ON Pin Activity	Package
FPF1504UCX	G4	20 mΩ	CMOS	YES	Active HIGH	4-Ball, WLCSP, 0.5 mm Pitch
FPF1504BUCX	G4	20 mΩ	CMOS	YES	Active HIGH	4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch
FPF1504LUCX	GZ	20 mΩ	CMOS	YES	Active LOW	4-Ball, WLCSP, 0.5 mm Pitch
FPF1504LBUCX	GZ	20 mΩ	CMOS	YES	Active LOW	4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch

### **Application Diagram**



NOTES: 1.  $C_{IN} = 1 \ \mu$ F, X5R, 0603, for example Murata GRM185R60J105KE26. 2.  $C_{OUT} = 1 \ \mu$ F, X5R, 0805, for example Murata GRM216R61A105KA01.

Figure 2. Typical Application

### **Pin Configurations**



Figure 3. 1 x 1 mm WLCSP Bumps Facing Down

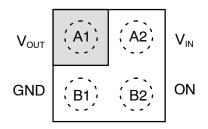


Figure 5. Pin Assignments (Top View)

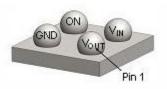


Figure 4. 1 x 1 mm WLCSP Bumps Facing Up

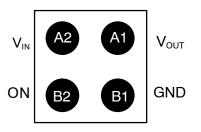


Figure 6. Pin Assignments (Bottom View)

### PIN DEFINITIONS

Pin #	Name	Description		
A1	V <sub>OUT</sub>	Switch Output		
A2	V <sub>IN</sub>	Supply Input; Input to the Power Switch		
B1	GND	Ground		
B2	ON	ON/OFF Control		

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter			Max.	Unit
V <sub>IN</sub>	V <sub>IN</sub> , V <sub>OUT</sub> , V <sub>ON</sub> to GND		-0.3	4.0	V
I <sub>SW</sub>	Maximum Continuous Switch Current			1.5	А
PD	Power Dissipation at T <sub>A</sub> = 25°C			1.0	W
T <sub>STG</sub>	Storage Junction Temperature			+150	°C
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
θја	Thermal Resistance, Junction-to-Ambient	n-to-Ambient 1S2P with 1 Thermal Via		95	°C/W
		1S2P without Thermal Via		187	
ESD	Electrostatic Discharge Capability	lectrostatic Discharge Capability Human Body Model, JESD22-A114			kV
		Charged Device Model, JESD22-C101	2		]

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min.	Max.	Unit
V <sub>IN</sub>	Supply Voltage	1.0	3.6	V
T <sub>A</sub>	Ambient Operating Temperature	-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

Unless otherwise noted,  $V_{IN}$  = 1.0 to 3.6 V,  $T_A$  = -40 to +85°C; Typical Values are at  $V_{IN}$  = 3.3 V and  $T_A$  = 25°C.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Units
SIC OPERAT	ION						
V <sub>IN</sub>	Supply Voltage			1.0		3.6	V
I <sub>Q(OFF)</sub>	Off Supply Current	FPF1504	V <sub>ON</sub> = GND, V <sub>OUT</sub> = Open		0.25		μΑ
		FPF1504L	V <sub>ON</sub> = V <sub>IN</sub> , V <sub>OUT</sub> = Open		0.3		
I <sub>SD(OFF)</sub> C	Off Switch Current	FPF1504	V <sub>ON</sub> = GND, V <sub>OUT</sub> = GND		0.25		
		FPF1504L	V <sub>ON</sub> = V <sub>IN</sub> , V <sub>OUT</sub> = GND		0.3		
Ι <sub>Q</sub>	Quiescent Current	FPF1504	$I_{OUT} = 0$ mA, $V_{IN} = 3.6$ V, $V_{ON} = V_{IN}$		0.08		
			IOUT = 0 mA, VON = VIH(MIN)		0.75		
		FPF1504L	I <sub>OUT</sub> = 0 mA, V <sub>IN</sub> = 3.6 V, V <sub>ON</sub> = GND		0.08		
		$I_{OUT} = 0 \text{ mA}, \text{ Von} = \text{Vil(max)}$		0.95			
R <sub>ON</sub>	On Resistance		$V_{IN}$ = 3.3 V, $I_{OUT}$ = 200 mA, $T_A$ = 25°C		15	30	mΩ
			$V_{IN}$ = 1.8 V, $I_{OUT}$ = 200 mA, $T_A$ = 25°C		20	40	
			$V_{IN}$ = 1.5 V, $I_{OUT}$ = 200 mA, T <sub>A</sub> = 25°C		30		
			$V_{IN}$ = 1.0 V, $I_{OUT}$ = 200 mA, $T_A$ = 25°C		40	80	
			V <sub>IN</sub> = 1.8 V, I <sub>OUT</sub> = 200 mA, T <sub>A</sub> = 85°C (Note 3)		35	50	
R <sub>PD</sub>	Output Discharge Pull-Down Resistance		$V_{ON} = 0 \text{ V or } V_{IN}, I_{OUT} = -20 \text{ mA}$		65	95	Ω
VIH	On Input Logic High Voltage	FPF1504		0.8			V
V <sub>IL</sub>	On Input Logic Low Voltage	FPF1504				0.3	
I <sub>ON</sub>	On Input Leakage		V <sub>ON</sub> = V <sub>IN</sub> or GND			1	μA
	RACTERISTICS				4		
t <sub>DON</sub>	Turn-On Delay (Note 4)	FPF1504	$R_L$ = 10 Ω, $C_L$ = 0.1 μF, V <sub>IN</sub> = 3.3 V, $T_A$ = 25°C		80		μs
t <sub>R</sub>	V <sub>OUT</sub> Rise Time (Note 4)	FPF1504	$V_{IN} = 3.3 \text{ V}, \text{ I}_{A} = 25^{\circ}\text{C}$		130		-
t <sub>ON</sub>	Turn–On Time (Note 4)	FPF1504			210		
t <sub>DON</sub>	Turn-On Delay (Note 4)	FPF1504	$R_L = 500 \Omega$ , $C_L = 0.1 \mu$ F,		70	100	μs
		FPF1504L	$V_{IN} = 3.3 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}$		95		
t <sub>R</sub>	V <sub>OUT</sub> Rise Time (Note 4) FPF1504				110	150	1
		FPF1504L			115		
t <sub>ON</sub>	Turn–On Time (Note 4)	FPF1504	7		180	250	
		FPF1504L			210		1
t <sub>DOFF</sub>	Turn-Off Delay (Note 4)	FPF1504	$R_L=10 \Omega, C_L=0.1 \mu F,$		25	30	μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time (Note 4)	FPF1504	$V_{IN} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$		2		
t <sub>OFF</sub>	Turn–Off Time (Note 4)	FPF1504			27	1	

### ELECTRICAL CHARACTERISTICS (continued)

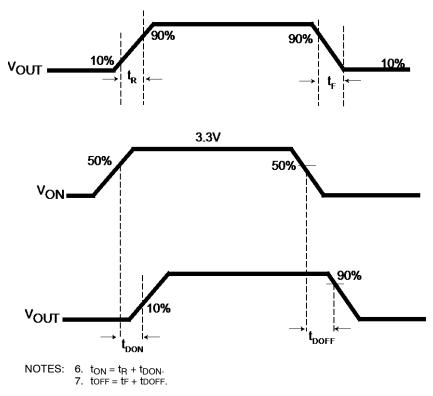
Unless otherwise noted,  $V_{IN}$  = 1.0 to 3.6 V,  $T_A$  = -40 to +85°C; Typical Values are at  $V_{IN}$  = 3.3 V and  $T_A$  = 25°C.

Symbol	Par	Parameter		Min.	Тур.	Max.	Units
DYNAMIC CHA	RACTERISTICS						
t <sub>DOFF</sub>	t <sub>DOFF</sub> Turn-Off Delay (Note 4)	FPF1504	$R_L = 500 \Omega$ , $C_L = 0.1 \mu$ F,		25		μs
		FPF1504L	V <sub>IN</sub> = 3.3 V, T <sub>A</sub> = 25°C		2		
t <sub>F</sub>	t <sub>F</sub> V <sub>OUT</sub> Fall Time (Note 4)	FPF1504			12		
		FPF1504L			14		
t <sub>OFF</sub>	(Note 4)	FPF1504			37		]
		FPF1504L		16	16		]

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. This parameter is guaranteed by design and characterization; not production tested.

4.  $t_{DON}/t_{DOFF}/t_R/t_F$  are defined in Figure 7. 5. Output discharge path is enabled during off.

#### **Timing Diagram – FPF1504**





### **TYPICAL PERFORMANCE CHARACTERISTICS FOR FPF1504**

Applicable to active high version only.

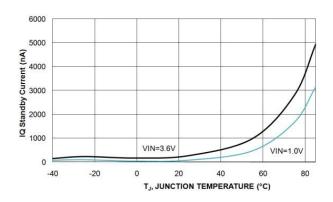


Figure 1. Shutdown Current vs. Temperature

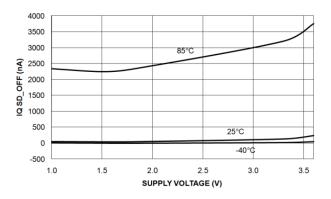


Figure 2. Shutdown Current vs. Supply Voltage

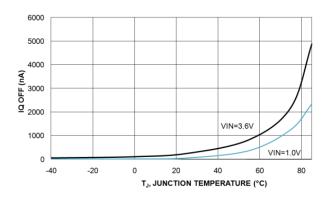


Figure 3. Off Supply Current vs. Temperature

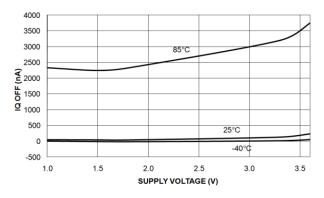


Figure 4. Off Supply Current vs. Supply Voltage

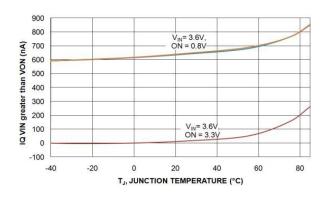
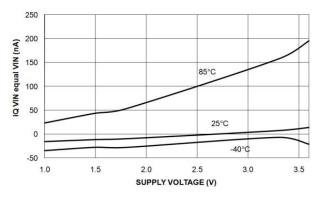
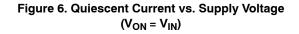


Figure 5. Quiescent Current vs. Temperature





### **TYPICAL PERFORMANCE CHARACTERISTICS FOR FPF1504**

Applicable to active high version only.

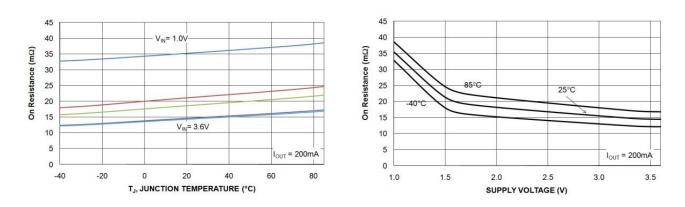
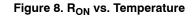


Figure 7. R<sub>ON</sub> vs. Temperature



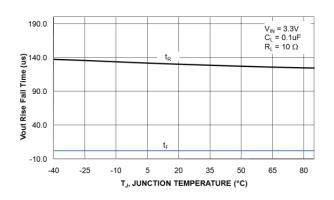


Figure 9. V<sub>OUT</sub> Rise/Fall Times vs. Temperature (R<sub>L</sub> = 10  $\Omega$ )

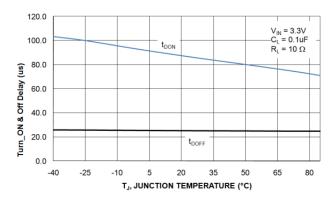
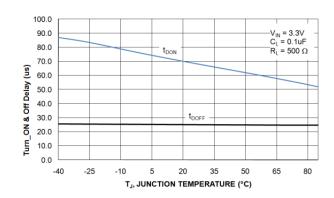
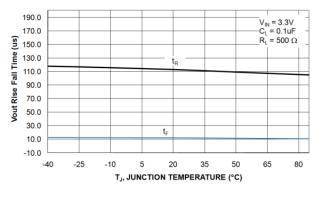
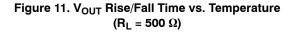
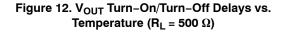


Figure 10. V<sub>OUT</sub> Turn–On/Turn–Off Delays vs. Temperature (R<sub>L</sub> = 10  $\Omega$ )









### **TYPICAL PERFORMANCE CHARACTERISTICS FOR FPF1504**

Applicable to active high version only.

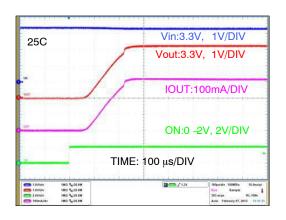


Figure 13. Turn–On Response (V<sub>IN</sub> = 3.3 V, C<sub>OUT</sub> = 0.1  $\mu$ F, R<sub>L</sub> = 10  $\Omega$ )

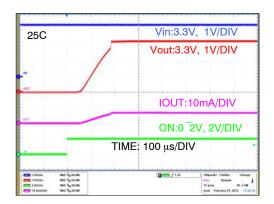


Figure 15. Turn–On Response (V<sub>IN</sub> = 3.3 V, C<sub>OUT</sub> = 0.1  $\mu$ F, R<sub>L</sub> = 500  $\Omega$ )

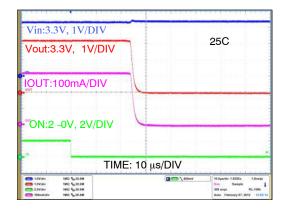


Figure 14. Turn–Off Response (V<sub>IN</sub> = 3.3 V, C<sub>OUT</sub> = 0.1  $\mu$ F, R<sub>L</sub> = 10  $\Omega$ )

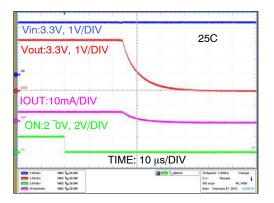


Figure 16. Turn–Off Response (V<sub>IN</sub> = 3.3 V, C<sub>OUT</sub> = 0.1  $\mu$ F, R<sub>L</sub> = 500  $\Omega$ )

### **APPLICATION INFORMATION**

#### Input Capacitor

IntelliMAX switches don't require an input capacitor. To reduce device inrush current, a 0.1  $\mu$ F ceramic capacitor, C<sub>IN</sub>, is recommended close to the VIN pin. A higher value of C<sub>IN</sub> can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

### **Output Capacitor**

IntelliMAX switches work without an output capacitor. If the applications parasitic board inductance forces  $V_{OUT}$  below GND when switching off, a 0.1  $\mu$ F capacitor,  $C_{OUT}$ , should be placed between  $V_{OUT}$  and GND.

#### Fall Time

Device output fall time can be calculated based on RC constant of external components as follows:

$$E_{\rm F} = R_{\rm L} \times C_{\rm L} \times 2.2$$
 (eq. 1

where  $t_F$  is 90% to 10% fall time,  $R_L$  is output, load and  $C_L$  is output capacitor.

The same equation works for a device with a pull–down output resistor, then  $R_L$  is replaced by a parallel connected pull–down and external output resistor combination, as follows:

$$t_{F} = \frac{R_{L} \times R_{PD} \times C_{L}}{R_{L} + R_{PD}} \times 2.2 \qquad (eq. 2)$$

where  $t_F$  is 90% to 10% fall time,  $R_L$  is output load,  $R_{PD}$  is output pull-down resistor (65  $\Omega$  typical), and  $C_L$  is the output capacitor.

### RECOMMENDED LAND PATTERN AND LAYOUT

For best thermal performance and minimal inductance and parasitic effects, it is recommended to keep input and output traces short and the capacitors as close to the device as possible. Below is a recommended layout for this device to achieve optimum performance.

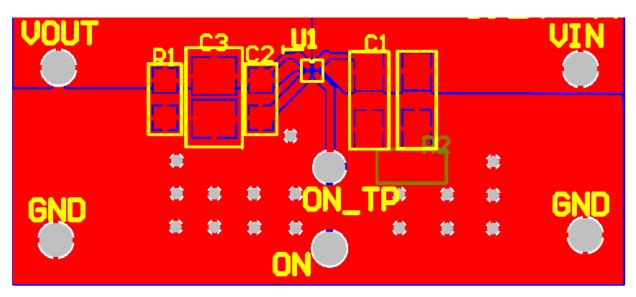


Figure 17. Recommended Land Pattern and Layout

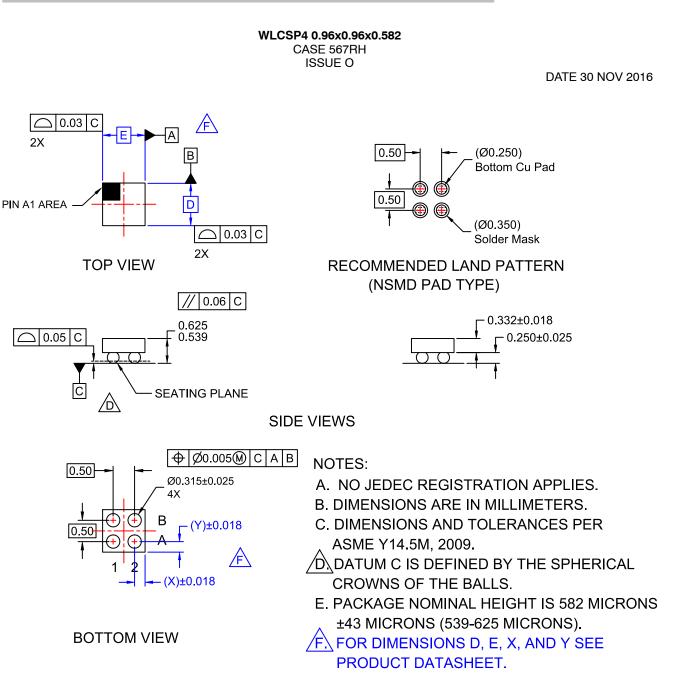
The following information applies to the WLCSP package dimensions on the next page:

### **PRODUCT-SPECIFIC DIMENSIONS**

Product	D	E	Х	Y	
FPF1504UCX					
FPF1504BUCX	960 μm ±30 μm	960 μm ±30 μm	0.230 mm	0.230 mm	
FPF1504LUCX				0.230 11111	
FPF1504LBUCX					

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